SLOS432-APRIL 2004









VERY LOW-POWER, HIGH-SPEED, RAIL-TO-RAIL INPUT AND OUTPUT **VOLTAGE-FEEDBACK OPERATIONAL AMPLIFIER**

FEATURES

- Very Low Quiescent Current: 750 µA (at 5 V)
- Rail-to-Rail Input and Output:
 - Common-Mode Input Voltage Extends 400 mV Beyond the Rails
 - Output Swings Within 150 mV From the Rails
- Wide -3 dB Bandwidth at 5 V:
 - 90-MHz @ Gain = +1, 40 MHz @ Gain = +2
- High Slew Rate: 35 V/µs
- Fast Settling Time (2-V Step):
 - 78 ns to 0.1%
 - 150 ns to 0.01%
- Low Distortion @ Gain = +2, V_O = 2-Vpp, 5 V:
 - -91 dBc at 100 kHz, -67 dBc at 1 MHz
- Input Offset Voltage: 2.5 mV (Max at 25°C)
- Output Current >30 mA (10- Ω Load, 5 V)
- Low Voltage Noise of 12.5 nV/√Hz
- Supply Voltages: $+2.7 \text{ V}, 3 \text{ V}, +5 \text{ V}, \pm 5 \text{ V}, +15 \text{ V}$
- Packages: SOT-23, MSOP, and SOIC

APPLICATIONS

- Portable/Battery-Powered Applications
- **High Channel Count Systems**
- **ADC Buffer**
- **Active Filters**
- **Current Sensing**

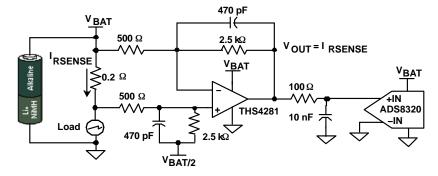
DESCRIPTION

Fabricated using the BiCom-II process, the THS4281 is a low-power, rail-to-rail input and output voltage-feedback operational amplifier designed to operate over a wide power supply range of 2.7-V to 15-V single supply, and ± 1.35 -V to ± 7.5 -V dual supply. Consuming only 750 µA with a unity gain bandwidth of 90 MHz and a high 35-V/µs slew rate, the THS4281 allows portable or other power-sensitive applications to realize high performance with minimal power. To ensure long battery life in portable applications, the quiescent current is trimmed to be less than 900 µA at 25°C, and 1 mA from -40°C to 85°C.

The THS4281 is a true single-supply amplifier with a specified common-mode input range of 400 mV beyond the rails. This allows for high-side current sensing applications without phase reversal concerns. Its output swings to within 40 mV from the rails with 10-k Ω loads, and 150 mV from the rails with 1-k Ω loads.

The THS4281 has a good 0.1% settling time of 78 ns, and 0.01% settling time of 150 ns. The low THD of -87 dBc at 100 kHz, coupled with a maximum offset voltage of less than 2.5 mV, makes the THS4281 a good match for high-resolution ADCs sampling less than 2 MSPS.

The THS4281 is offered in a space-saving SOT-23-5 package, a small MSOP-8 package, and the industry standard SOIC-8 package.



High-Side, Low Power Current-Sensing System



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

| | | UNIT | | | |
|--|---|------------------------------|--|--|--|
| Supply voltage | , V_{S-} to V_{S+} | 16.5 V | | | |
| Input voltage, V_I $\pm V_S \pm 0.5 \text{ V}$ | | | | | |
| Differential inpu | ut voltage, V _{ID} | ±2 V | | | |
| Output current, | I _O | ±100 mA | | | |
| Continuous por | wer dissipation | See Dissipation Rating Table | | | |
| Maximum junct | 150°C | | | | |
| Maximum junct | tion temperature, continuous operation, long term reliability ⁽²⁾ T _J | 125°C | | | |
| Storage tempe | rature range, T _{stg} | -65°C to 150°C | | | |
| Lead temperate | ure 1,6 mm (1/16 inch) from case for 10 seconds | 300°C | | | |
| | НВМ | 3500 V | | | |
| ESD ratings | CDM | 1500 V | | | |
| | MM | 100 V | | | |

⁽¹⁾ The absolute maximum ratings under any condition is limited by the constraints of the silicon process. Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

RECOMMENDED OPERATING CONDITIONS

| | | MIN | MAX | UNIT |
|--|---------------|-------|-------|------|
| Supply voltage ()/ and)/ | Dual supply | ±1.35 | ±8.25 | \/ |
| Supply voltage, (V _{S+} and V _{S-}) | Single supply | 2.7 | 16.5 | V |

DISSIPATION RATINGS TABLE PER PACKAGE

| PACKAGE | θдс | θ _{JC} (°C/W) | | ING ⁽²⁾ | |
|---------|---------------|------------------------|-----------------------|-----------------------|--|
| FACKAGE | (∘C/W) θJC | (°C/W) | T _A < 25°C | T _A = 85°C | |
| DBV (5) | 55 | 255.4 | 391 mW | 156 mW | |
| D (8) | 38.3 | 97.5 | 1.02 W | 410 mW | |
| DGK (8) | 71.5 | 180.8 | 553 mW 221 mW | | |

⁽¹⁾ This data was taken using the JEDEC standard High-K test PCB.

⁽²⁾ The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device. recommended operating conditions.

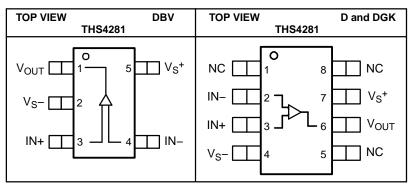
⁽²⁾ Power rating is determined with a junction temperature of 125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and long term reliability.



PACKAGING/ORDERING INFORMATION

| PACKAGED DEVICES | DEVICE MARKING | PACKAGE TYPE | TRANSPORT MEDIA, QUANTITY |
|------------------|----------------|--------------|---------------------------|
| THS4281DBVT | AON | COT 22 F | Tape and Reel, 250 |
| THS4281DBVR | AON | SOT-23 - 5 | Tape and Reel, 3000 |
| THS4281D | | SOIC - 8 | Rails, 75 |
| THS4281DR | | 3010 - 6 | Tape and Reel, 2500 |
| THS4281DGK | 400 | MCOD 0 | Rails, 75 |
| THS4281DGKR | A00 | MSOP - 8 | Tape and Reel, 2500 |

PIN CONFIGURATION



NOTE: NC indicates there is no internal connection to these pins.



ELECTRICAL CHARACTERISTICS, V_S = 3 V (V_{S+} = 3 V, V_{S-} = GND) G = +2, R_F = 2.49 k Ω , R_L = 1 k Ω to 1.5 V, unless otherwise noted

| | | TYP | | OVER | TEMPER | ATURE | |
|-------------------------------|---|-----------|----------|----------------|------------------|---------------------------------------|-------------|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX |
| AC PERFORMANCE | | | | | | | |
| | $G = +1$, $V_O = 100 \text{ mVpp}$, $R_F = 34 \Omega$ | 83 | | | | MHz | Тур |
| Cmall Cianal Bandwidth | $G = +2$, $V_O = 100$ mVpp, $R_F = 1.65 \text{ k}\Omega$ | 40 | | | | MHz | Тур |
| Small-Signal Bandwidth | $G = +5$, $V_O = 100$ mVpp, $R_F = 1.65 \text{ k}\Omega$ | 8 | | | | MHz | Тур |
| | $G = +10$, $V_O = 100 \text{ mVpp}$, $R_F = 1.65 \text{ k}\Omega$ | 3.8 | | | | MHz | Тур |
| 0.1 dB Flat Bandwidth | $G = +2$, $V_O = 100 \text{ mVpp}$, $R_F = 1.65 \text{ k}\Omega$ | 20 | | | | MHz | Тур |
| Full-Power Bandwidth | $G = +2$, $V_O = 2 Vpp$ | 8 | | | | MHz | Тур |
| Slew Rate | G = +1, V _O = 2-V Step | 26 | | | | V/μs | Тур |
| OICVV IVAIC | G = -1, V _O = 2-V Step | 27 | | | | V/μs | Тур |
| Settling time to 0.1% | G = -1, V _O = 1-V Step | 80 | | | | ns | Тур |
| Settling time to 0.01% | G = -1, V _O = 1-V Step | 155 | | | | ns | Тур |
| Rise/Fall Times | $G = +1$, $V_O = 2-V$ Step | 55 | | | | ns | Тур |
| Harmonic Distortion | $G = +2$, $V_O = 2 Vpp$ | | | | | | |
| Second Harmonic Distortion | $f = 1 \text{ MHz}, R_L = 1 \text{ k}\Omega$ | -52 | | | | dBc | Тур |
| Third Harmonic Distortion | - 1 W 12, N - 1 N22 | -52 | | | | dBc | Тур |
| Second Harmonic Distortion | $f = 100 \text{ kHz}, R_L = 1 \text{ k}\Omega$ | -69 | | | | dBc | Тур |
| Third Harmonic Distortion | 1 = 100 KHZ, KL = 1 KS2 | -71 | | | | dBc | Тур |
| THD + N | V _O = 1 Vpp, f = 10 kHz | 0.003 | | | | % | Тур |
| TID + N | $V_O = 2 \text{ Vpp, } f = 10 \text{ kHz}$ | 0.03 | | | | % | Тур |
| Differential Gain (NTSC/PAL) | $G = +2$, $R_L = 150 Ω$ | 0.05/0.08 | | | | % | Тур |
| Differential Phase (NTSC/PAL) | G = +2, K _L = 130 52 | 0.25/0.35 | | | | ۰ | Тур |
| Input Voltage Noise | f = 100 kHz | 12.5 | | | | nA/√ Hz | Тур |
| Input Current Noise | f = 100 kHz | 1.5 | | | | pA/√ Hz | Тур |
| DC PERFORMANCE | | | | | | | |
| Open-Loop Voltage Gain (AOL) | | 95 | | | | dB | Тур |
| Input Offset Voltage | | 0.5 | 2.5 | 3.5 | 3.5 | mV | Max |
| Average Offset Voltage Drift | | | | ±7 | ±7 | μV/°C | Тур |
| Input Bias Current | V - 1.5.V | 0.5 | 0.8 | 1 | 1 | μΑ | Max |
| Average Bias Current Drift | V _{CM} = 1.5 V | | | ±2 | ±2 | nA/°C | Тур |
| Input Offset Current | | 0.1 | 0.4 | 0.5 | 0.5 | μА | Max |
| Average Offset Current Drift | | | | ±2 | ±2 | nA/°C | Тур |
| INPUT CHARACTERISTICS | | | | | | · · · · · · · · · · · · · · · · · · · | |
| Common-Mode Input Range | | -0.4/3.4 | -0.3/3.3 | -0.1/3.1 | -0.1/3.1 | V | Min |
| Common-Mode Rejection Ratio | V _{CM} = 0 V to 3 V | 92 | 75 | 70 | 70 | dB | Min |
| Input Resistance | Common-mode | 100 | | | | MΩ | Тур |
| Input Capacitance | Common-mode/Differential | 0.8/1.2 | | | | pF | Тур |



ELECTRICAL CHARACTERISTICS, $V_S = 3 \text{ V } (V_{S+} = 3 \text{ V}, V_{S-} = \text{GND})$ (continued)

G = +2, R_F = 2.49 k Ω , R_L = 1 k Ω to 1.5 V, unless otherwise noted

| | | TYP | | OVER | TEMPERA | ATURE | |
|--------------------------------|---|-----------|-----------|----------------|------------------|-------|-------------|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX |
| OUTPUT CHARACTERISTICS | | | | | | | |
| Output Valtage Swing | $R_L = 10 \text{ k}\Omega$ | 0.04/2.96 | | | | V | Тур |
| Output Voltage Swing | $R_L = 1 \text{ k}\Omega$ | 0.1/2.9 | 0.14/2.86 | 0.2/2.8 | 0.2/2.8 | V | Min |
| Output Current (Sourcing) | R _L = 10 Ω | 23 | 18 | 15 | 15 | mA | Min |
| Output Current (Sinking) | $R_L = 10 \Omega$ | 29 | 22 | 19 | 19 | mA | Min |
| Output Impedance | f = 1 MHz | 1 | | | | Ω | Тур |
| POWER SUPPLY | | • | | | • | | |
| Maximum Operating Voltage | | 3 | 16.5 | 16.5 | 16.5 | V | Max |
| Minimum Operating Voltage | | 3 | 2.7 | 2.7 | 2.7 | V | Min |
| Maximum Quiescent Current | | 0.75 | 0.9 | 0.98 | 1.0 | mA | Max |
| Minimum Quiescent Current | | 0.75 | 0.6 | 0.57 | 0.55 | mA | Min |
| Power Supply Rejection (+PSRR) | V _{S+} = 3.25 V to 2.75 V, V _{S-} = 0 V | 90 | 70 | 65 | 65 | dB | Min |
| Power Supply Rejection (-PSRR) | $V_{S+} = 3 \text{ V}, V_{S-} = 0 \text{ V to } 0.65 \text{ V}$ | 90 | 70 | 65 | 65 | dB | Min |



ELECTRICAL CHARACTERISTICS, V_S = 5 V (V_{S+} = 5 V, V_{S-} = GND) G = +2, R_F = 2.49 k Ω , R_L = 1 k Ω to 2.5 V, unless otherwise noted

| | | TYP | OVER TEMPERATURE | | | | | |
|-------------------------------|---|-----------|------------------|----------------|------------------|--------------------|-------------|--|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX | |
| AC PERFORMANCE | | | | | | | | |
| | $G = +1$, $V_O = 100 \text{ mVpp}$, $R_F = 34 \Omega$ | 90 | | | | MHz | Тур | |
| Small-Signal Bandwidth | $G = +2$, $V_O = 100 \text{ mVpp}$, $R_F = 2 \text{ k}\Omega$ | 40 | | | | MHz | Тур | |
| Sitiali-Signal Bandwidth | $G = +5, V_O = 100 \text{ mVpp},$ $R_F = 2 \text{ k}\Omega$ | 8 | | | | MHz | Тур | |
| | $G = +10$, $V_O = 100$ mVpp, $R_F = 2$ k Ω | 3.8 | | | | MHz | Тур | |
| 0.1-dB Flat Bandwidth | $G = +2$, $V_O = 100 \text{ mVpp}$, $R_F = 2 \text{ k}\Omega$ | 20 | | | | MHz | Тур | |
| Full-Power Bandwidth | $G = +2$, $V_O = 2 Vpp$ | 9 | | | | MHz | Тур | |
| Slew Rate | G = +1, V _O = 2-V Step | 31 | | | | V/μs | Тур | |
| Siew Rate | G = -1, V _O = 2-V Step | 34 | | | | V/μs | Тур | |
| Settling Time to 0.1% | G = -1, V _O = 2-V Step | 78 | | | | ns | Тур | |
| Settling Time to 0.01% | G = -1, V _O = 2-V Step | 150 | | | | ns | Тур | |
| Rise/Fall Times | G = +1, V _O = 2-V Step | 48 | | | | ns | Тур | |
| Harmonic Distortion | G = +2, V _O = 2 Vpp | | | | | | | |
| Second Harmonic Distortion | (ANU - D ALO | -67 | | | | dBc | Тур | |
| Third Harmonic Distortion | $f = 1 \text{ MHz}, R_L = 1 \text{ k}\Omega$ | -76 | | | | dBc | Тур | |
| Second Harmonic Distortion | (400 LL B 41 C | -92 | | | | dBc | Тур | |
| Third Harmonic Distortion | $f = 100 \text{ kHz}, R_L = 1 \text{ k}\Omega$ | -106 | | | | dBc | Тур | |
| T115 11 | V _O = 2 Vpp, f = 10 kHz | 0.0009 | | | | % | Тур | |
| THD + N | V _O = 4 Vpp, f = 10 kHz | 0.0005 | | | | % | Тур | |
| Differential Gain (NTSC/PAL) | | 0.11/0.17 | | | | % | Тур | |
| Differential Phase (NTSC/PAL) | $G = +2$, $R_L = 150 \Omega$ | 0.11/0.14 | | | | ٥ | Тур | |
| Input Voltage Noise | f = 100 kHz | 12.5 | | | | nV/√ Hz | Тур | |
| Input Current Noise | f = 100 kHz | 1.5 | | | | pA/√ Hz | Тур | |
| DC PERFORMANCE | - | ' | | 1 | ! | | | |
| Open-Loop Voltage Gain (AOL) | | 105 | 85 | 80 | 80 | dB | Min | |
| Input Offset Voltage | | 0.5 | 2.5 | 3.5 | 3.5 | mV | Max | |
| Average Offset Voltage Drift | | | | ±7 | ±7 | μV/°C | Тур | |
| Input Bias Current | 7, 25,7 | 0.5 | 0.8 | 1 | 1 | μΑ | Max | |
| Average Bias Current Drift | $V_{CM} = 2.5 \text{ V}$ | | | ±2 | ±2 | nA/°C | Тур | |
| Input Offset Current | | 0.1 | 0.4 | 0.5 | 0.5 | μΑ | Max | |
| Average Offset Current Drift | | | | ±2 | ±2 | nA/°C | Тур | |



ELECTRICAL CHARACTERISTICS, $V_S = 5 \text{ V}$ ($V_{S+} = 5 \text{ V}$, $V_{S-} = \text{GND}$) (continued)

G = +2, $\rm R_F$ = 2.49 k $\Omega,~\rm R_L$ = 1 k Ω to 2.5 V, unless otherwise noted

| | | TYP | OVER TEMPERATURE | | | | | |
|--------------------------------|---|-----------|------------------|----------------|------------------|-------|-------------|--|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX | |
| INPUT CHARACTERISTICS | • | | | | | | | |
| Common-Mode Input Range | | -0.4/5.4 | -0.3/5.3 | -0.1/5.1 | -0.1/5.1 | V | Min | |
| Common-Mode Rejection Ratio | V _{CM} = 0 V to 5 V | 100 | 85 | 80 | 80 | dB | Min | |
| Input Resistance | Common-mode | 100 | | | | МΩ | Тур | |
| Input Capacitance | Common-mode/Differential | 0.8/1.2 | | | | pF | Тур | |
| OUTPUT CHARACTERISTICS | | | | | | | | |
| Output Voltage Swing | $R_L = 10 \text{ k}\Omega$ | 0.04/4.96 | | | | V | Тур | |
| Output Voltage Swing | $R_L = 1 k\Omega$ | 0.15/4.85 | 0.2/4.8 | 0.25/4.75 | 0.25/4.75 | V | Min | |
| Output Current (Sourcing) | $R_L = 10 \Omega$ | 33 | 24 | 20 | 20 | mA | Min | |
| Output Current (Sinking) | R _L = 10 Ω | 44 | 30 | 25 | 25 | mA | Min | |
| Output Impedance | f = 1 MHz | 1 | | | | Ω | Тур | |
| POWER SUPPLY | | | | | | | | |
| Maximum Operating Voltage | | 5 | 16.5 | 16.5 | 16.5 | V | Max | |
| Minimum Operating Voltage | | 5 | 2.7 | 2.7 | 2.7 | V | Min | |
| Maximum Quiescent Current | | 0.75 | 0.9 | 0.98 | 1.0 | mA | Max | |
| Minimum Quiescent Current | | 0.75 | 0.6 | 0.57 | 0.55 | mA | Min | |
| Power Supply Rejection (+PSRR) | $V_{S+} = 5.5 \text{ V to } 4.5 \text{ V},$ $V_{S-} = 0 \text{ V}$ | 100 | 80 | 75 | 75 | dB | Min | |
| Power Supply Rejection (-PSRR) | $V_{S+} = 5 \text{ V}, V_{S-} = 0 \text{ V to } 1.0 \text{ V}$ | 100 | 80 | 75 | 75 | dB | Min | |



ELECTRICAL CHARACTERISTICS, $V_s = \pm 5 \text{ V}$

G = +2, R_F = 2.49 k Ω , R_L = 1 k Ω , unless otherwise noted

| | | TYP | OVER TEMPERATURE | | | | | |
|-------------------------------|--|-------------|------------------|----------------|------------------|--------------------|-------------|--|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX | |
| AC PERFORMANCE | | | | | | | | |
| | G = +1, V_0 = 100 mVpp, R_F = 34 Ω | 95 | | | | MHz | Тур | |
| Small Signal Bandwidth | $G = +2, V_O = 100 \text{ mVpp}$ | 40 | | | | MHz | Тур | |
| Small-Signal Bandwidth | $G = +5, V_O = 100 \text{ mVpp}$ | 8 | | | | MHz | Тур | |
| | $G = +10, V_O = 100 \text{ mVpp}$ | 3.8 | | | | MHz | Тур | |
| 0.1-dB Flat Bandwidth | $G = +2, V_O = 100 \text{ mVpp}$ | 20 | | | | MHz | Тур | |
| Full-Power Bandwidth | G = +1, V _O = 2 Vpp | 9.5 | | | | MHz | Тур | |
| Claur Data | G = +1, V _O = 2-V Step | 35 | | | | V/μs | Тур | |
| Slew Rate | G = -1, V _O = 2-V Step | 35 | | | | V/μs | Тур | |
| Settling Time to 0.1% | G = -1, V _O = 2-V Step | 78 | | | | ns | Тур | |
| Settling Time to 0.01% | G = -1, V _O = 2-V Step | 140 | | | | ns | Тур | |
| Rise/Fall Times | G = +1, V _O = 2-V Step | 45 | | | | ns | Тур | |
| Harmonic Distortion | G = +2, V _O = 2 Vpp | | | | | | | |
| Second Harmonic Distortion | f AMIL D ALO | -69 | | | | dBc | Тур | |
| Third Harmonic Distortion | $f = 1 \text{ MHz}, R_L = 1 \text{ k}\Omega$ | -76 | | | | dBc | Тур | |
| Second Harmonic Distortion | (400 H D 41 0 | -93 | | | | dBc | Тур | |
| Third Harmonic Distortion | $f = 100 \text{ kHz}, R_L = 1 \text{ k}\Omega$ | -107 | | | | dBc | Тур | |
| THD + N | V _O = 2 Vpp, f = 10 kHz | 0.0009 | | | | % | Тур | |
| | V _O = 8 Vpp, f = 10 kHz | 0.0003 | | | | % | Тур | |
| Differential Gain (NTSC/PAL) | | 0.03/0.03 | | | | % | Тур | |
| Differential Phase (NTSC/PAL) | $G = +2$, $R_L = 150 Ω$ | 0.08/0.1 | | | | ۰ | Тур | |
| Input Voltage Noise | f = 100 kHz | 12.5 | | | | nV/√ Hz | Тур | |
| Input Current Noise | f = 100 kHz | 1.5 | | | | pA/√ Hz | Тур | |
| DC PERFORMANCE | • | ' | | * | ' | | | |
| Open-Loop Voltage Gain (AOL) | | 108 | 90 | 85 | 85 | dB | Min | |
| Input Offset Voltage | | 0.5 | 2.5 | 3.5 | 3.5 | mV | Max | |
| Average Offset Voltage Drift | | | | ±7 | ±7 | μV/°C | Тур | |
| Input Bias Current | | 0.5 | 0.8 | 1 | 1 | μΑ | Max | |
| Average Bias Current Drift | V _{CM} = 0 V | | | ±2 | ±2 | nA/°C | Тур | |
| Input Offset Current | | 0.1 | 0.4 | 0.5 | 0.5 | μΑ | Max | |
| Average Offset Current Drift | | | | ±2 | ±2 | nA/°C | Тур | |
| INPUT CHARACTERISTICS | | | | • | • | | | |
| Common-Mode Input Range | | ±5.4 | ±5.3 | ±5.1 | ±5.1 | V | Min | |
| Common-Mode Rejection Ratio | V _{CM} = -5 V to +5 V | 107 | 90 | 85 | 85 | dB | Min | |
| Input Resistance | Common-mode | 100 | | | | MΩ | Тур | |
| Input Capacitance | Common-mode / Differential | 0.8/1.2 | | | | pF | Тур | |
| OUTPUT CHARACTERISTICS | | · · · · · · | | | | · | | |
| Output Voltogo Swing | $R_L = 10 \text{ k}\Omega$ | ±4.93 | | | | V | Тур | |
| Output Voltage Swing | $R_L = 1 \text{ k}\Omega$ | ±4.8 | ±4.6 | ±4.5 | ±4.5 | V | Min | |
| Output Current (Sourcing) | R _L = 10 Ω | 48 | 35 | 30 | 30 | mA | Min | |
| Output Current (Sinking) | R _L = 10 Ω | 60 | 45 | 40 | 40 | mA | Min | |
| Output Impedance | f = 1 MHz | 1 | | | | Ω | Тур | |



ELECTRICAL CHARACTERISTICS, V_{S} = ± 5 V (continued)

G = +2, R_F = 2.49 k Ω , R_L = 1 k Ω , unless otherwise noted

| | | TYP | OVER TEMPERATURE | | | | | |
|--------------------------------|--|------|------------------|----------------|------------------|-------|-------------|--|
| PARAMETER | CONDITIONS | 25°C | 25°C | 0°C to 70°C | -40°C to 85°C | UNITS | MIN/ MAX | |
| POWER SUPPLY | | | , | | | | | |
| Maximum Operating Voltage | | ±5 | ±8.25 | ±8.25 | ±8.25 | V | Max | |
| Minimum Operating Voltage | | ±5 | ±1.35 | ±1.35 | ±1.35 | V | Min | |
| Maximum Quiescent Current | | 0.8 | 0.93 | 1.0 | 1.05 | mA | Max | |
| Minimum Quiescent Current | | 0.8 | 0.67 | 0.62 | 0.6 | mA | Min | |
| Power Supply Rejection (+PSRR) | $V_{S+} = 5.5 \text{ V to } 4.5 \text{ V}, V_{S-} = 5.0 \text{ V}$ | 100 | 80 | 75 | 75 | dB | Min | |
| Power Supply Rejection (-PSRR) | $V_{S+} = 5 \text{ V}, V_{S-} = -5.5 \text{ V to } -4.5 \text{ V}$ | 100 | 80 | 75 | 75 | dB | Min | |



TYPICAL CHARACTERISTICS

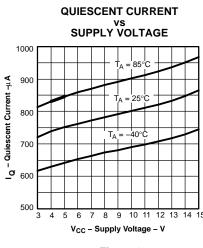


Figure 1.

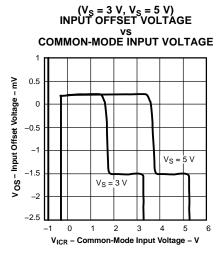


Figure 2.

POSITIVE VOLTAGE HEADROOM

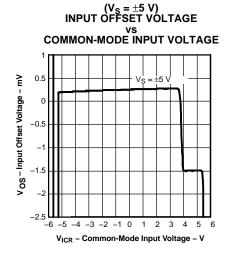


Figure 3.

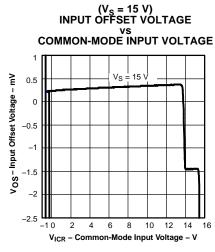


Figure 4.

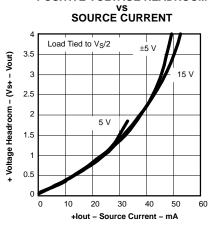


Figure 5.

 $(V_S = \pm 5 \text{ V})$ OUTPUT VOLTAGE

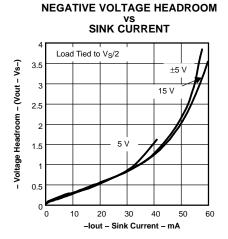


Figure 6.

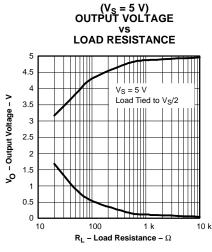


Figure 7.

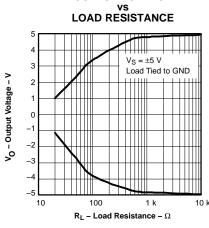


Figure 8.

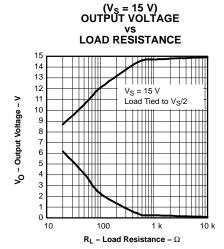
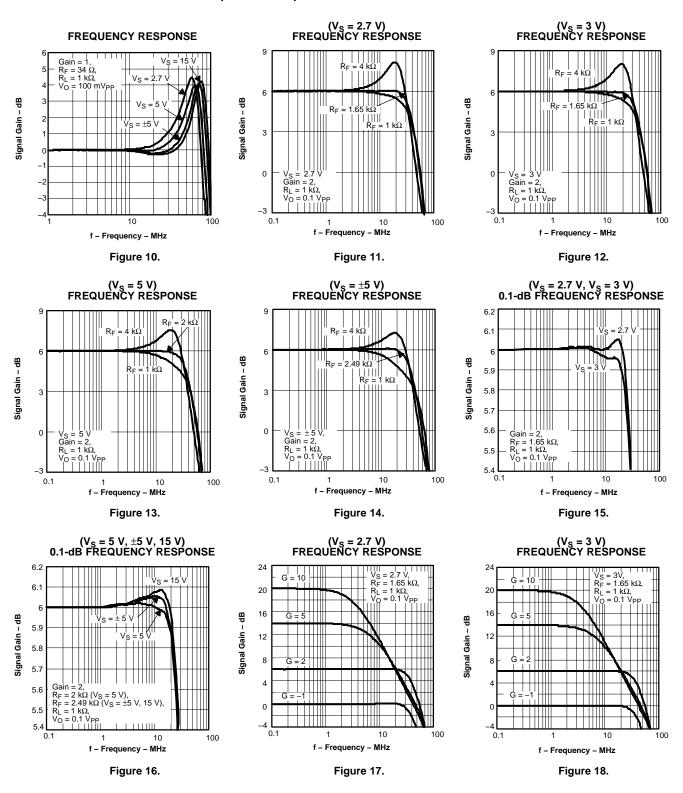
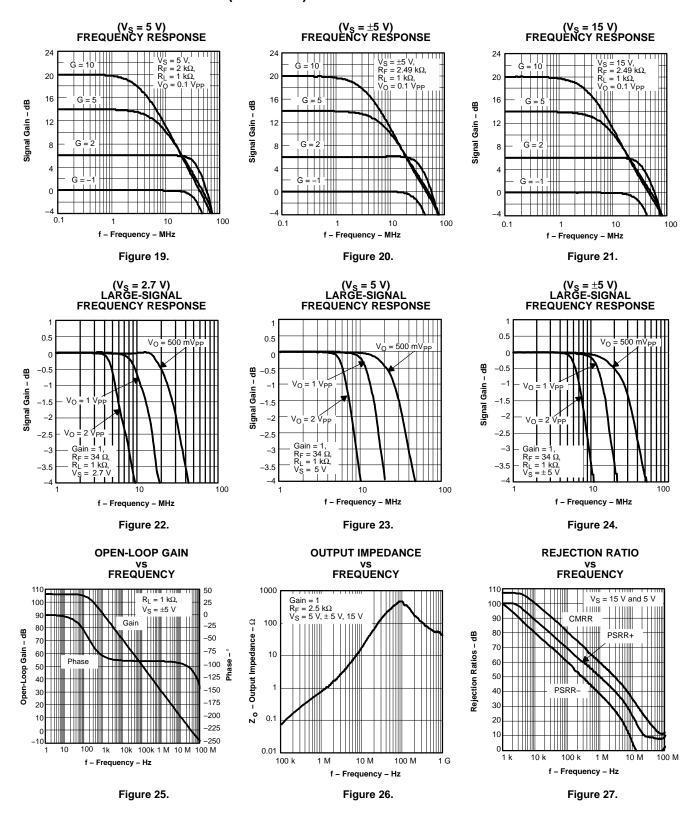


Figure 9.

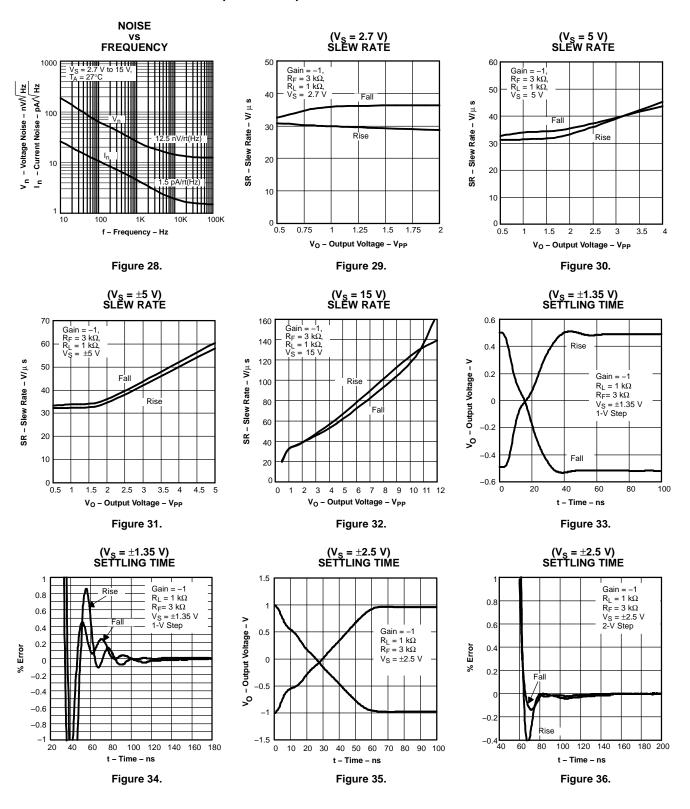




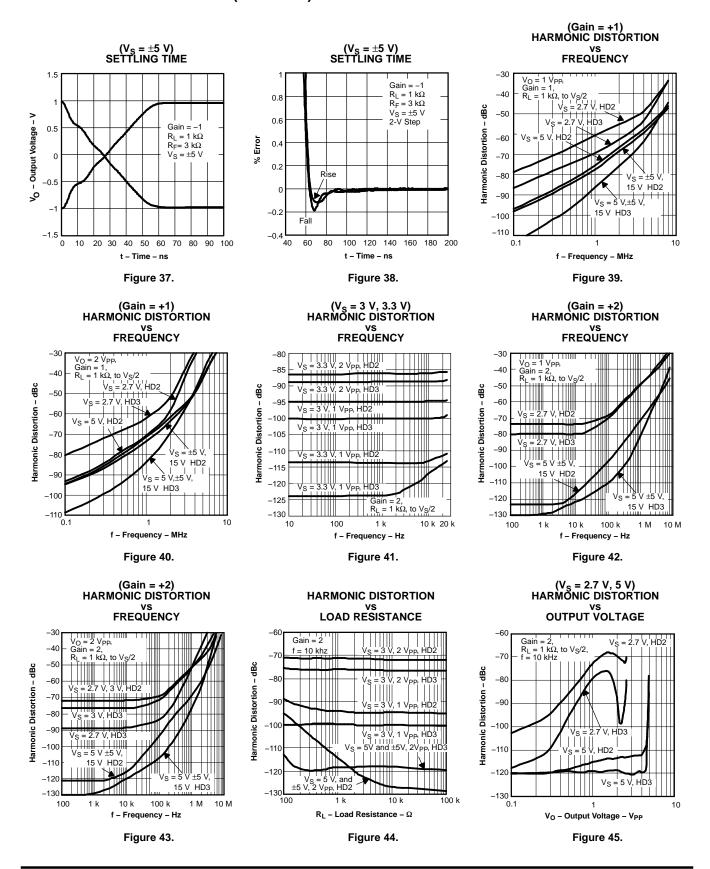














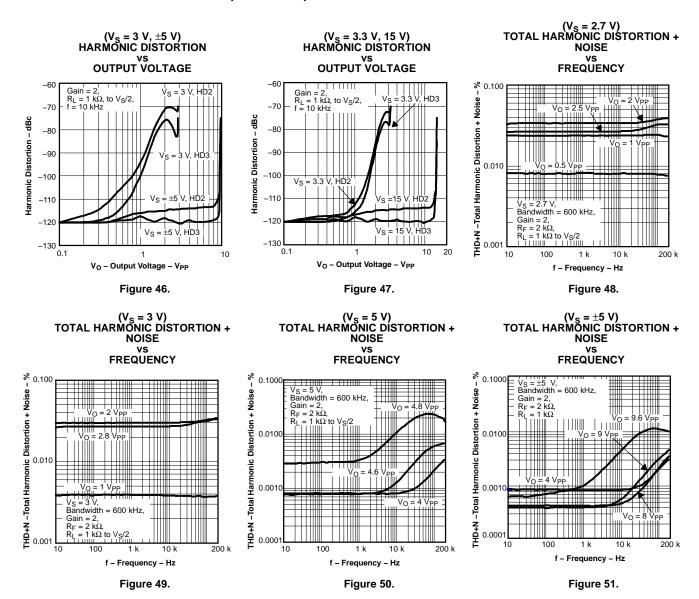




Figure 57.

TYPICAL CHARACTERISTICS (continued)

Figure 55.

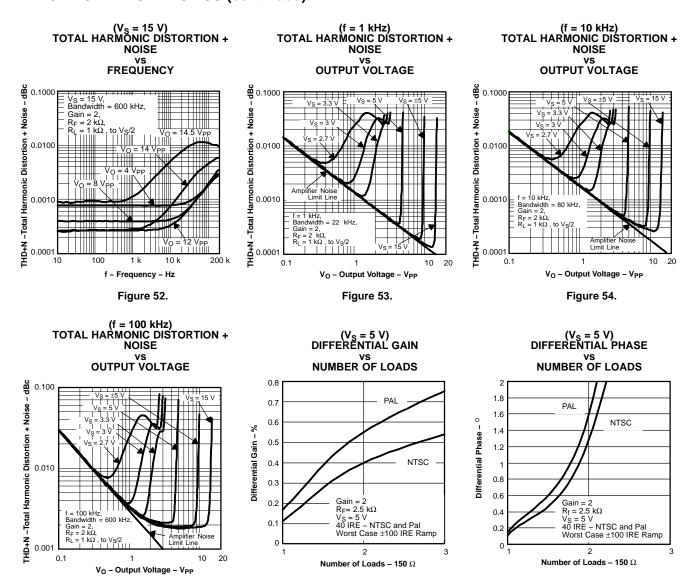
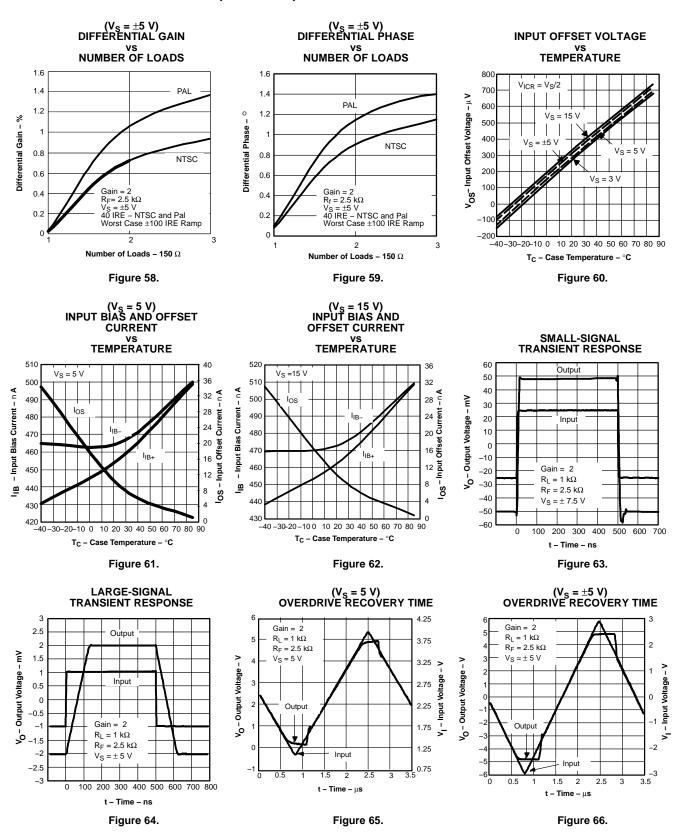


Figure 56.







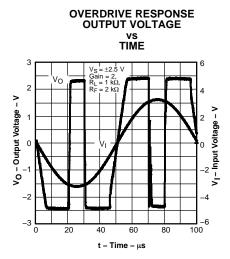


Figure 67.



APPLICATION INFORMATION

HIGH-SPEED OPERATIONAL AMPLIFIERS

The THS4281 is a unity gain stable rail-to-rail input and output voltage feedback operational amplifier designed to operate from a single 2.7-V to 16.5-V power supply.

Applications Section Contents

- Wideband, Noninverting Operation
- · Wideband, Inverting Gain Operation
- Video Drive Circuits
- Single-Supply Operation
- Power Supply Decoupling Techniques and Recommendations
- Active Filtering With the THS4281
- Driving Capacitive Loads
- Board Layout
- Thermal Analysis
- Additional Reference Material
- Mechanical Package Drawings

WIDEBAND, NONINVERTING OPERATION

Figure 68 shows the noninverting gain configuration of 2 V/V used to demonstrate the typical performance curves.

Voltage feedback amplifiers can use a wide range of resistors values to set their gain with minimal impact on frequency response. Larger-valued resistors decrease loading of the feedback network on the output of the amplifier, but may cause peaking and instability. For a gain of +2, feedback resistor values between 1 k Ω and 4 k Ω are recommended for most applications. However, as the gain increases, the use of even higher feedback resistors can be used to conserve power. This is due to the inherent nature of amplifiers becoming more stable as the gain increases, at the expense of bandwidth. Figure 69 and Figure 70 show the THS4281 using feedback resistors of 10 k Ω and 100 k Ω . Be cautioned that using such high values with high-speed amplifiers is not typically recommended, but under certain conditions, such as high gain and good high-speed-PCB layout practices, such resistances can be used.

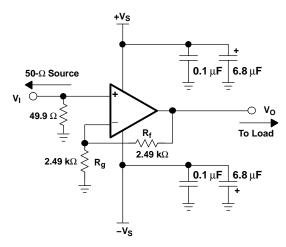


Figure 68. Wideband, Noninverting Gain Configuration

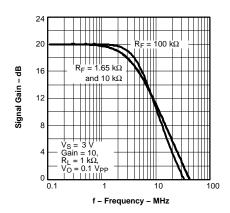


Figure 69. Signal Gain vs Frequency, $V_S = 3 \text{ V}$

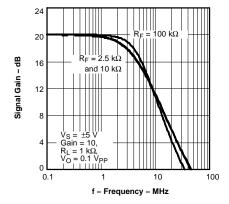


Figure 70. Signal Gain vs Frequency, $V_S = \pm 5 \text{ V}$



WIDEBAND, INVERTING OPERATION

Figure 71 shows a typical inverting configuration where the input and output impedances and noise gain from Figure 68 are retained with an inverting circuit gain of -1 V/V.

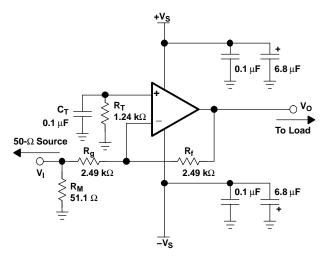


Figure 71. Wideband, Inverting Gain Configuration

In the inverting configuration, some key design considerations must be noted. One is that the gain resistor (R_a) becomes part of the signal channel input impedance. If the input impedance matching is desired (which is beneficial whenever the signal is coupled through a cable, twisted pair, long PC board trace, or other transmission line conductors), R_a may be set equal to the required termination value and Rf adjusted to give the desired gain. However, care must be taken when dealing with low inverting gains, as the resultant feedback resistor value can present a significant load to the amplifier output. For example, an inverting gain of 2, setting R_g to 49.9 Ω for input matching, eliminates the need for R_M but requires a $100-\Omega$ feedback resistor. The $100-\Omega$ feedback resistor, in parallel with the external load, causes excessive loading on the amplifier output. To eliminate this excessive loading, it is preferable to increase both R_a and R_f values, as shown in Figure 71, and then achieve the input matching impedance with a third resistor (R_M) to ground. The total input impedance is the parallel combination of R_a and R_M.

Another consideration in inverting amplifier design is setting the bias current cancellation resistor (R_T) on the noninverting input. If the resistance is set equal to the total dc resistance presented to the device at the inverting terminal, the output dc error (due to the input bias currents) is reduced to the input offset current multiplied by R_T . In Figure 71, the dc source impedance presented at the inverting terminal is 2.49 $k\Omega$ || (2.49 $k\Omega$ + 25.3 Ω) \cong 1.24 $k\Omega$. To reduce the additional high-frequency noise introduced by the resistor at the noninverting input, R_T is bypassed with a 0.1-µF capacitor to ground (C_T).

SINGLE-SUPPLY OPERATION

The THS4281 is designed to operate from a single 2.7-V to 16.5-V power supply. When operating from a single power supply, care must be taken to ensure the input signal and amplifier are biased appropriately to allow for the maximum output voltage swing and not violate V_{ICR} . The circuits shown in Figure 72 shows inverting and noninverting amplifiers configured for single-supply operation.

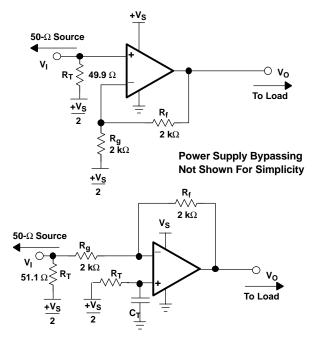


Figure 72. DC-Coupled Single Supply Operation



APPLICATION CIRCUITS

Active Filtering With the THS4281

High performance active filtering with the THS4281 is achievable due to the amplifier's good slew rate, wide bandwidth, and voltage feedback architecture. Several options are available for high-pass, low-pass, bandpass, and bandstop filters of varying orders. Filters can be quite complex and time consuming to design. Several books and application reports are available to help design active filters. But, to help simplify the process and minimize the chance of miscalculations, Texas Instruments has developed a filter design program called FilterPro™. FilterPro is available for download at no cost from TI's Web site (www.ti.com).

The two most common low-pass filter circuits used are the Sallen-Key filter and the Multiple Feedback (MFB)-aka Rauch filter. FilterPro was used to determine a 2-pole Butterworth response filter with a corner (-3 dB) frequency of 100 kHz which is shown in Figure 73 and Figure 74. One of the advantages of the MFB filter, a much better high frequency rejection, is clearly shown in the response shown in Figure 75. This is due to the inherent R-C filter to ground being the first elements in the design of the MFB filter. The Sallen-Key design also has an R-C filter, but the capacitor connects directly to the output. At very high frequencies, where the amplifier's access loop gain is decreasing, the ability of the amplifier to reject high frequencies is severely reduced and allows the high frequency signals to pass through the system. One other advantage of the MFB filter is the reduced sensitivity in component variation. This is important when using real-world components where capacitors can easily have ±10% variations.

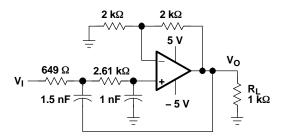


Figure 73. Second-Order Sallen-Key 100-kHz Butterworth Filter, Gain = 2 V/V

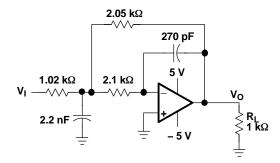


Figure 74. Second-Order MFB 100-kHz Butterworth Filter, Gain = 2 V/V

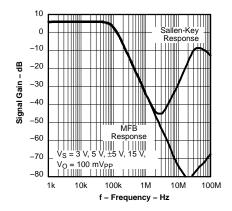


Figure 75. Second-Order 100-kHz Active Filter Response

Driving Capacitive Loads

One of the most demanding, and yet common, load conditions for an op amp is capacitive loading. Often. the capacitive load is the input of an A/D converter, including additional external capacitance, which may be recommended to improve A/D linearity. A high-speed, high open-loop gain amplifier like the THS4281 can be susceptible to instability and peaking when a capacitive load is placed directly on the output. When the amplifier's open-loop output resistance is considered, this capacitive load introduces an additional pole in the feedback path that decreases the phase margin. When the primary considerations are frequency response flatness, pulse response fidelity, or distortion, a simple and effective solution is to isolate the capacitive load from the feedback loop by inserting a small series isolation resistor (10 Ω to 25 Ω) between the amplifier output and the capacitive load.



Power Supply Decoupling Techniques and Recommendations

Power supply decoupling is a critical aspect of any high-performance amplifier design. Careful decoupling provides higher quality ac performance. The following guidelines ensure the highest level of performance.

- Place decoupling capacitors as close to the power supply inputs as possible, with the goal of minimizing the inductance.
- Placement priority should put the smallest valued capacitors closest to the device.
- Use of solid power and ground planes is recommended to reduce the inductance along power supply return current paths (with the exception of the areas underneath the input and output pins as noted below).
- 4. A bulk decoupling capacitor is recommended (6.8 to 22 μ F) within 1 inch, and a ceramic (0.1 μ F) within 0.1 inch of the power input pins.

NOTE:

The bulk capacitor may be shared by other op amps.

BOARD LAYOUT

Achieving optimum performance with a high frequency amplifier like the THS4281 requires careful attention to board layout parasitics and external component types. See the EVM layout figures in the Design Tools Section.

Recommendations that optimize performance include:

- 1. Minimize parasitic capacitance to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and inverting input pins can cause instability and on the noninverting input, it can react with the source impedance to cause unintentional band limiting. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.
- Minimize the distance (< 0.1 inch) from the power supply pins to high frequency 0.1-μF decoupling capacitors. Avoid narrow power and ground traces to minimize inductance. The power supply connections should always be decoupled as described above.
- Careful selection and placement of external components preserves the high frequency performance of the THS4281. Resistors should be a low reactance type. Surface-mount resistors work best and allow a tighter overall layout.

- Metal-film, axial-lead resistors can also provide good high frequency performance. Again, keep their leads and PC board trace length as short as possible. Never use wire wound type resistors in a high frequency application. Because the output pin and inverting input pin are the most sensitive to parasitic capacitance, always position the feedback and series output resistor, if any, as close as possible to the output pin. Other network components, such as noninverting input termination resistors, should also be placed close to the package. Excessively high resistor values can create significant phase lag that can degrade performance. Keep resistor values as low as possible, consistent with load-driving considerations. It is suggested that a good starting point for design is to set the R_f to 2 $k\Omega$ for low-gain, noninverting applications. Doing this automatically keeps the resistor noise terms reasonable and minimizes the effect of parasitic capacitance.
- 4. Connections to other wideband devices on the board should be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50 mils to 100 mils) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and set RISO from the plot of recommended R_{ISO} vs capacitive load. Low parasitic capacitive loads (<4 pF) may not need an R_(ISO), because the THS4281 is nominally compensated to operate at unity gain (+1 V/V) with a 2-pF capacitive load. Higher capacitive loads without an R_(ISO) are allowed as the signal gain increases. If a long trace is required, and the 6-dB signal loss intrinsic to a doubly terminated transmission line is acceptable, implement a matched impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques). A matching series resistor into the trace from the output of the THS4281 is used as well as a terminating shunt resistor at the input of the destination device. Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device: this total effective impedance should be set to match the trace impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, long trace а can series-terminated at the source end only. Treat the trace as a capacitive load in this case, and set the series resistor value as shown in the plot of R_(ISO) vs capacitive load. If the input impedance of the destination device is low, there is signal attenuation due to the voltage divider formed by $R_{(ISO)}$ into the terminating impedance.



A 50- Ω environment is normally not necessary onboard, and in fact a higher impedance environment improves distortion as shown in the distortion versus load plots.

5. Socketing a high speed part like the THS4281 is not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket can create a troublesome parasitic network which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS4281 onto the board.

THERMAL ANALYSIS

The THS4281 does not incorporate automatic thermal shutoff protection, so the designer must take care to ensure that the design does not violate the absolute maximum junction temperature of the device. Failure may result if the absolute maximum junction temperature of 150° C is exceeded. For long-term dependability, the junction temperature should not exceed 125°C.

The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using the following formula.

$$\mathsf{P}_{\mathsf{Dmax}} = \frac{\mathsf{T}_{\mathsf{max}} - \mathsf{T}_{\mathsf{A}}}{\theta_{\mathsf{JA}}}$$

where

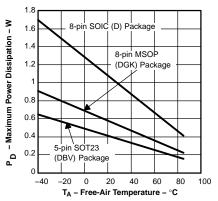
 P_{Dmax} is the maximum power dissipation in the amplifier (W). T_{max} is the absolute maximum junction temperature (°C).

T_A is the ambient temperature (°C).

 $\theta_{JA} = \theta_{JC} + \theta_{CA}$

 θ_{JC} is the thermal coefficient from the silicon junctions to the case (°C/W).

 θ_{CA} is the thermal coefficient from the case to ambient air (°C/W).



 $\theta_{JA}=97.5^{\circ}\text{C/W}$ for 8-Pin SOIC (D) $\theta_{JA}=180.8^{\circ}\text{C/W}$ for 8-Pin MSOP (DGK) $\theta_{JA}=255.4^{\circ}\text{C/W}$ for 5-Pin SOT-23 (DBV)

T_J = 125°C, No Airflow

Figure 76. Maximum Power Dissipation vs
Ambient Temperature

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to consider not only quiescent power dissipation, but also dynamic power dissipation. Often maximum power dissipation is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS value can provide a reasonable analysis.

DESIGN TOOLS

Evaluation Fixtures and Application Support Information

Texas Instruments is committed to providing its customers with the highest quality of applications support. To support this goal, an evaluation board has been developed for the THS4281 operational amplifier. The evaluation board is available and easy to use allowing for straight-forward evaluation of the device. These evaluation board can be obtained by ordering through the Texas Instruments Web site, www.ti.com, or through your local Texas Instruments Sales Representative. A schematic for the evaluation board is shown in Figure 77 with their default component values. Unpopulated footprints are shown to provide insight into design flexibility.

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. This is particularly true for video and RF amplifier circuits where parasitic capacitance and inductance can have a major effect on circuit performance. A SPICE model for the THS4281 device is available through either the Texas Instruments Web site (www.ti.com) or as one model on a disk from the Texas Instruments Product Information Center (1-800-548-6132). The PIC is also available for design assistance and detailed product information at this number. These models do a good job of predicting small-signal ac and transient performance under a wide variety of operating conditions. They are not intended to model the distortion characteristics of the amplifier, nor do they attempt to distinguish between the package types in their small-signal ac performance. Detailed information about what is and is not modeled is contained in the model file itself.



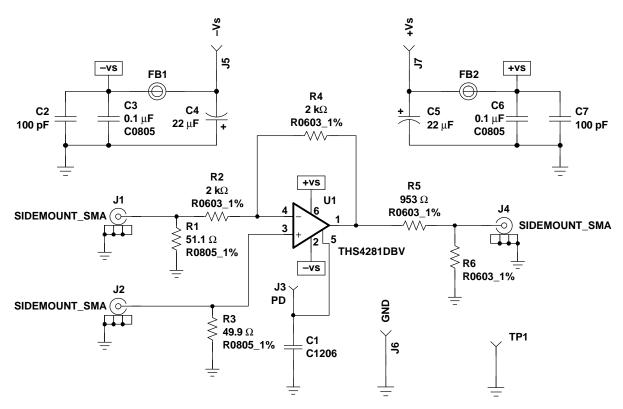


Figure 77. THS4281EVM Schematic

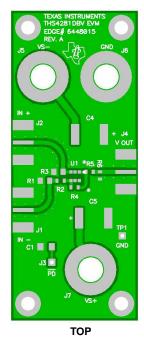
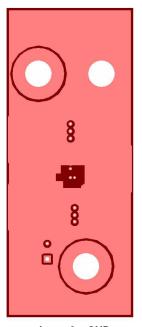


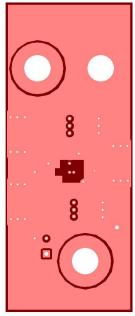
Figure 78. THS4281EVM Layout (Top Layer and Silkscreen Layer)



Layer 2 – GND

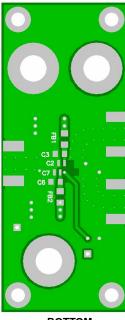
Figure 79. THS4281EVM Board Layout





Layer 3 - GND

Figure 80. THS4281EVM Board Layout



BOTTOM

Figure 81. THS4281EVM Board Layout



BILL OF MATERIALS

THS4281DBV EVM

| ITEM | DESCRIPTION | SMD SIZE | REFERENCE DESIG- NATOR | PCB QTY. | MANUFACTURER'S PART NUMBER ⁽¹⁾ | DISTRIBUTOR'S PART NUMBER |
|------|--|-------------|------------------------------|-------------|--|--------------------------------|
| 1 | Bead, Ferrite, 3A, 80 Ω | 1206 | FB1, FB2 | 2 | (STEWARD) HI1206N800R-00 | (DIGI-KEY) 240-1010-1-ND |
| 2 | OPEN | 1206 | C1 | 1 | | |
| 3 | Cap, 22 μF, tanatalum, 25 V, 10% | D | C4, C5 | 2 | (AVX) TAJD226K025R | (GARRETT) TAJD226K025R |
| 4 | Cap, 0.1 µF, ceramic, X7R, 50V | 0805 | C3, C6 | 2 | (AVX) 08055C104KAT2A | (GARRETT) 08055C104KAT2A |
| 5 | Cap, 100 pF, ceramic, 5%, 150V | AQ12 | C2, C7 | 2 | (AVX) AQ12EM101JAJME | (TTI) AQ12EM101JAJME |
| 6 | OPEN | 0603 | R6 | 1 | | |
| 7 | Resistor, 2 KΩ, 1/10W, 1% | 0603 | R2, R4 | 2 | (PHYCOMP) 9C06031A2001FKHFT | (GARRETT) 9C06031A2001FKHFT |
| 8 | Resistor, 953 Ω, 1/10W, 1% | 0603 | R5 | 1 | (PHYCOMP) 9C06031A9530FKRFT | (GARRETT) 9C06031A9530FKRFT |
| 9 | Resistor, 51.1 Ω, 1/8W, 1% | 0805 | R1 | 1 | (PHYCOMP) 9C08052A51R1FKHFT | (GARRETT) 9C08052A51R1FKHFT |
| 10 | Resistor, 49.9 Ω, 1/8W, 1% | 0805 | R3 | 1 | (PHYCOMP) 9C08052A49R9FKHFT | (GARRETT) 9C08052A49R9FKHFT |
| 11 | Jack, banana receptance, 0.25" diameter hole | | J5, J6, J7 | 3 | (HH SMITH) 101 | (NEWARK) 35F865 |
| 12 | OPEN | | J3 | 1 | | |
| 13 | Test point, black | | TP1 | 1 | (KEYSTONE) 5001 | (DIGI-KEY) 5001K-ND |
| 14 | Connector, edge, SMA PCB JACK | | J1, J2, J4 | 3 | (JOHNSON) 142-0701-801 | (NEWARK) 90F2624 |
| 15 | Standoff, 4-40 HEX, 0.625" length | | | 4 | (KEYSTONE) 1804 | (NEWARK) 89F1934 |
| 16 | Screw, PHILLIPS, 4-40, 0.250" | | | 4 | SHR-0440-016-SN | |
| 17 | IC, THS4281 | | U1 | 1 | (TI) THS4281DBV | |
| 18 | Board, printed circuit | | | 1 | (TI) EDGE # 6448015 Rev.A | |

⁽¹⁾ The manufacturer's part numbers are used for test purposes only.

ADDITIONAL REFERENCE MATERIALS

- PowerPAD Made Easy, application brief, (SLMA004)
- PowerPAD Thermally Enhanced Package, technical brief (SLMA002)
- Active Low-Pass Filter Design, application report (SLOA049)
- FilterPro MFB and Sallen-Key Low-Pass Filter Design Program, application report (SBFA001)





19-May-2005

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | e Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|------|----------------|---------------------------|------------------|------------------------------|
| THS4281D | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DGK | ACTIVE | MSOP | DGK | 8 | 100 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DGKR | ACTIVE | MSOP | DGK | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DGKRG4 | ACTIVE | MSOP | DGK | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| THS4281DRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

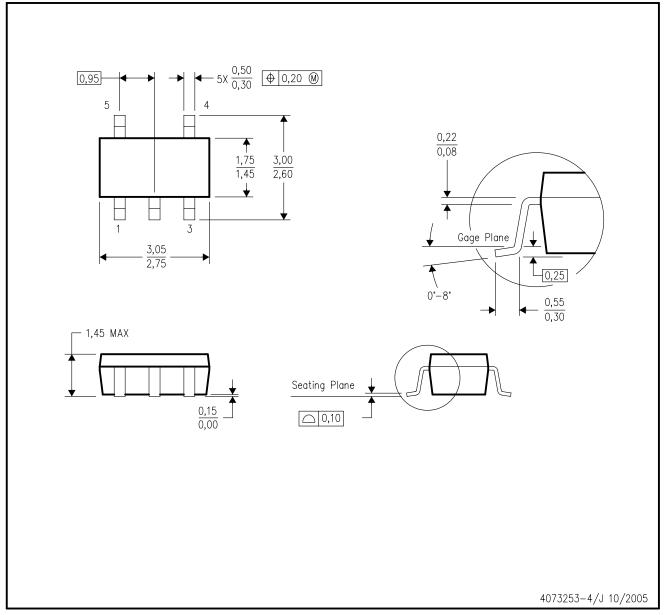
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



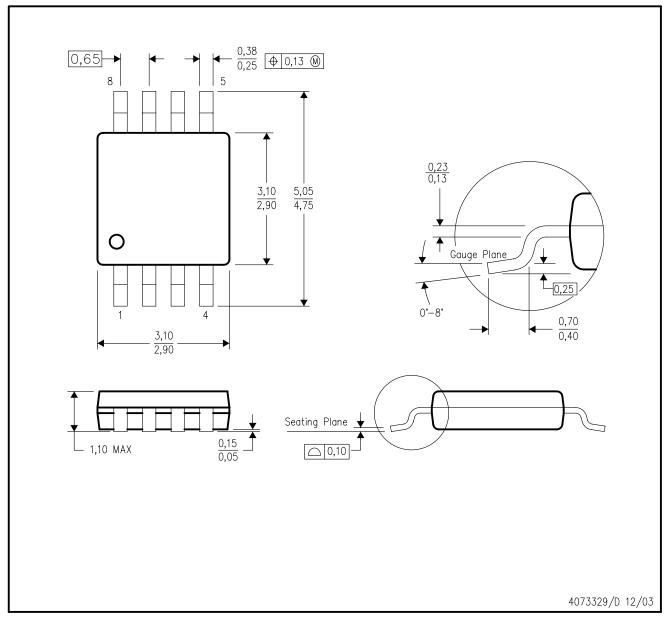
NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



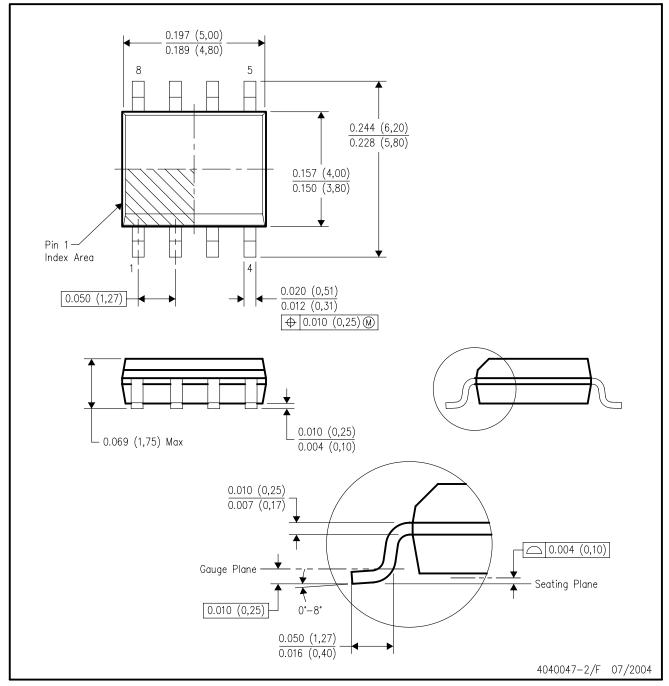
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AA.



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